

C1206C399C1GACTU

Aliases (C1206C399C1GAC7800) SMD Comm COG, Ceramic, 3.9 pF, +/-0.25 pF, 100 VDC, COG, SMD, MLCC, Ultra-Stable, Low Loss, Class I, 1206, 1.5 mm



Click here for the 3D model.

General Information	
Series	SMD Comm COG
Style	SMD Chip
Description	SMD, MLCC, Ultra-Stable, Low Loss, Class I
Features	Ultra-Stable, Low Loss, Class I
RoHS	Yes
Termination	Tin
Marking	No
AEC-Q200	No
Typical Component Weight	15 mg
Shelf Life	78 Weeks
MSL	1

Sp	ecifications	
Ca	pacitance	3.9 pF
Me	easurement Condition	1 MHz 1.0Vrms
Tol	lerance	+/-0.25 pF
Vo	ltage DC	100 VDC
Die	electric Withstanding Voltage	250 VDC
Tei	mperature Range	-55/+125°C
Tei	mp. Coefficient	COG
Re	pacitance Change with ference to +25°C and 0 VDC oplied (TCC)	30 ppm/C, 1MegaHz 1.0Vrms
Dis	ssipation Factor	0.1% 1 MHz 1.0Vrms
Agir	jing Rate	0% Loss/Decade Hour
Ins	sulation Resistance	100 GOhms

 Dimensions

 Chip Size
 1206

 L
 3.2mm +/-0.2mm

 W
 1.6mm +/-0.2mm

 T
 0.78mm +/-0.10mm

 S
 1.5mm MIN

 B
 0.5mm +/-0.25mm

Packaging Specifications Packaging

Packaging Quantity

T&R, 180mm, Plastic Tape 4000

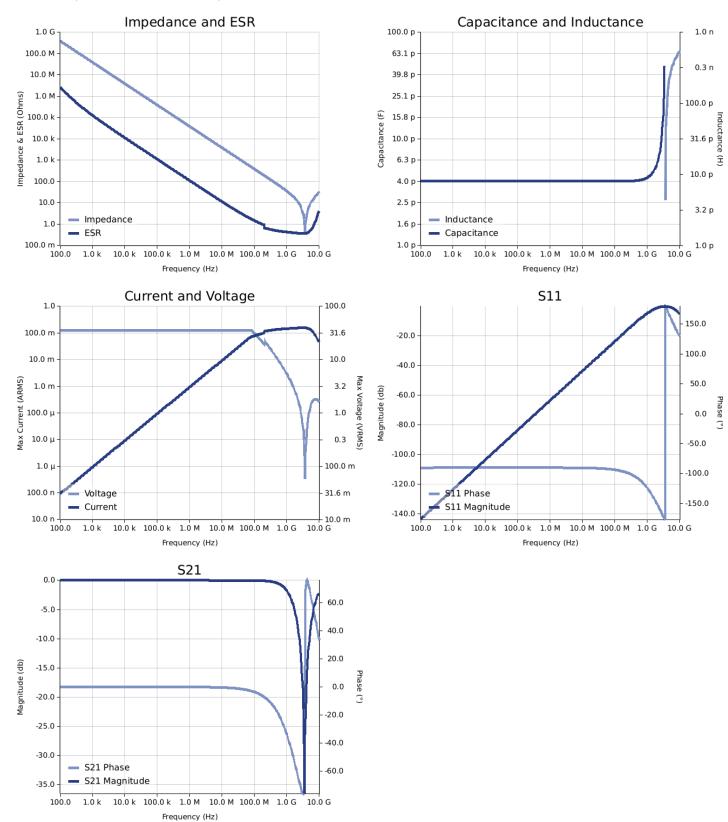
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Simulations

For the complete simulation environment please visit K-SIM.





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These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for hipple klipple current younge vs. requericy plots is the ESR at an bient temperature.
 The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
 The effects shown herein are based on measured data from a multiple part sample of the parts in question.
 Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
 The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages are not combined with voltages.
- generated at any other harmonics.
 Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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If you have any questions please contact K-SIM.